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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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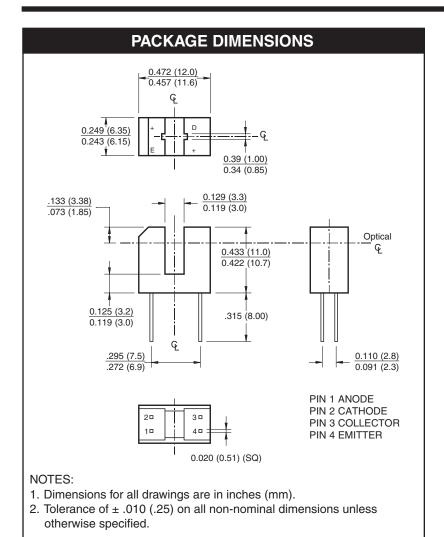


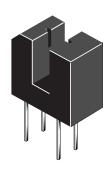


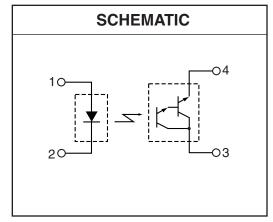




H22B4 H22B5 H22B6







DESCRIPTION

The H22B4, H22B5 and H22B6 consist of a gallium arsenide infrared emitting diode coupled with a silicon photodarlington in a plastic housing. The packaging system is designed to optimize the mechanical resolution, coupling efficiency, ambient light rejection, cost and reliability. The gap in the housing provides a means of interrupting the signal with an opaque material, switching the output from an "ON" to an "OFF" state.

FEATURES

- Opaque housing
- Low cost
- 035" apertures
- High I_{C(ON)}



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ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise specified)								
Parameter	Symbol	Rating	Unit					
Operating Temperature	T _{OPR}	-55 to +100	°C					
Storage Temperature	T _{STG}	-55 to +100	°C					
Soldering Temperature (Iron) ^(2,3 and 4)	T _{SOL-I}	240 for 5 sec	°C					
Soldering Temperature (Flow) ^(2 and 3)	T _{SOL-F}	260 for 10 sec	°C					
INPUT (EMITTER)								
Continuous Forward Current	I _F	50	mA					
Reverse Voltage	V _R	6	V					
Power Dissipation ⁽¹⁾	P _D	100	mW					
OUTPUT (SENSOR)								
Collector to Emitter Voltage	V _{CEO}	55	V					
Emitter to Collector Voltage	V _{ECO}	6	V					
Collector Current	I _C	40	mA					
Power Dissipation $(T_C = 25^{\circ}C)^{(1)}$	P _D	150	mW					

NOTES:

- 1. Derate power dissipation linearly 1.33 mW/°C above 25°C.
- 2. RMA flux is recommended.
- 3. Methanol or isopropyl alcohols are recommended as cleaning agents.
- 4. Soldering iron 1/16" (1.6 mm) minimum from housing.



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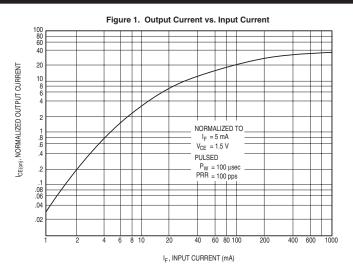
ELECTRICAL/OPTICAL CHARACTERISTICS (T _A =25°C)									
PARAMETER	TEST CONDITIONS	SYMBOL	DEVICES	MIN	TYP	MAX	UNITS		
INPUT (EMITTER)									
Forward Voltage	I _F = 60 mA	V _F	All	_	_	1.7	V		
Reverse Breakdown Voltage	I _R = 10 μA	V _R	All	6.0	_	_	V		
Reverse Leakage Current	V _R = 3 V	I _R	All	_	_	1.0	μΑ		
OUTPUT (SENSOR)									
Emitter to Collector Breakdown	$I_F = 100 \mu A, E_e = 0$	BV _{ECO}	All	7.0	_	_	V		
Collector to Emitter Breakdown	$I_{C} = 1 \text{ mA}, E_{e} = 0$	BV _{CEO}	All	55	_	_	V		
Collector to Emitter Leakage	$V_{CE} = 45 \text{ V}, E_e = 0$	I _{CEO}	All	_	_	100	nA		
COUPLED On-State Collector Current	I _F = 2 mA, V _{CE} = 1.5 V		H22B4	0.5	_	_	mA		
			H22B5	1.0	_	_			
			H22B6	2.0	_	_			
	I _F = 5 mA, V _{CE} = 1.5 V		H22B4	2.5	_	_			
		I _{C(ON)}	H22B5	5.0	_	_			
			H22B6	10	_	_			
	I _F = 10 mA, V _{CE} = 1.5 V		H22B4	7.5	_	_			
			H22B5	14	_	_			
			H22B6	25	_	_			
Saturation Voltage	$I_F = 10 \text{ mA}, I_C = 1.8 \text{ mA}$	V	All	_	_	1.0	V		
	$I_F = 60 \text{ mA}, I_C = 50 \text{ mA}$	V _{CE(SAT)}	H22B5/6	_	_	1.5	V		
Turn-On Time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V},$ $R_L = 750\Omega$		All	_	45	_	μs		
	$I_F = 60 \text{ mA}, V_{CC} = 5 \text{ V},$ $R_L = 75\Omega$	t _{on}	All	_	7	_			
Turn-Off Time	$I_F = 10 \text{ mA}, V_{CC} = 5 \text{ V},$ $R_L = 750\Omega$		All	_	250	_	- μs		
	$I_F = 60 \text{ mA}, V_{CC} = 5 \text{ V},$ $R_L = 75\Omega$	t _{off}	All	_	45	_			

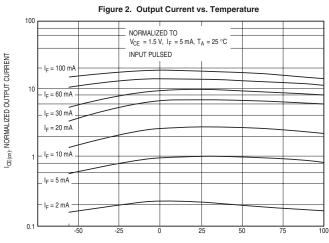


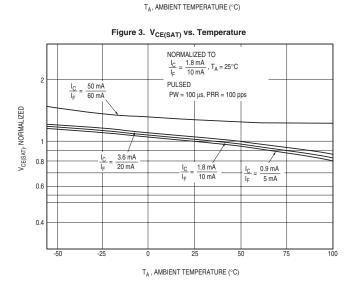
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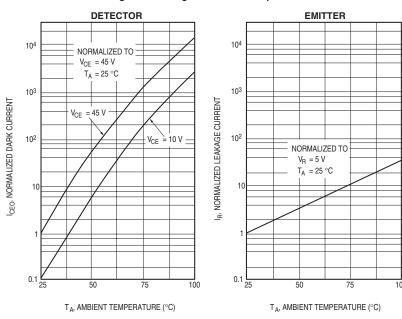


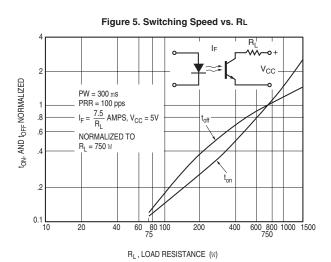
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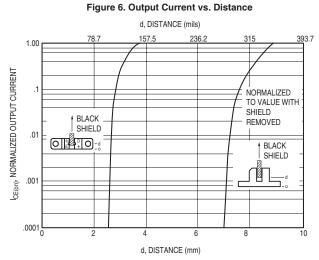
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Figure 4. Leakage Current vs. Temperature









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